TOSHIBA CMOS DIGITAL INTEGRATED CIRCUIT SILICON MONOLITHIC

TC7SH14F, TC7SH14FU

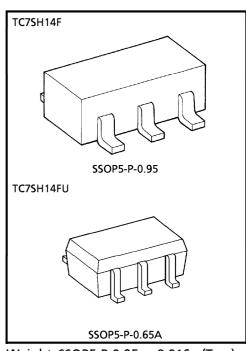
SCHMITT INVERTER

The TC7SH14 is an advanced high speed CMOS SCHMITT INVERTER fabricated with silicon gate CMOS technology. It achieves the high speed operation similar to equivalent Bipolar Schottky TTL while maintaining the CMOS low power dissipation. Pin configuration and function are the same as the TC7SH14 but the inputs have hysteresis and with its schmitt trigger function, the TC7SH14 can be used as a line receivers which will receive slow input signals.

An input protection circuit ensures that 0V to 7V can be applied to the input pins without regard to the supply voltage. This device can be used to interface 5V to 3V system and two supply systems such as battery back up. This circuit prevents device destruction due to mismatched supply and input voltages.

FEATURES

- High Speed $\cdots t_{pd} = 5.5$ ns (Typ.) at $V_{CC} = 5V$
- Low Power Dissipation \cdots I_{CC} = 2μ A (Max.) at Ta = 25°C
- High Noise Immunity V_{NIH} = V_{NIL} = 28% V_{CC} (Min.)
- Power Down Protection is provided on all inputs.
- Balanced Propagation Delays ······ t_{pLH}=t_{pHL}
- Wide Operation Voltage Range ··· V_{CC} (opr) = 2V~5.5V

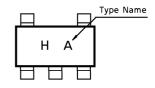


Weight SSOP5-P-0.95 : 0.016g (Typ.) SSOP5-P-0.65A : 0.006g (Typ.)

MAXIMUM RATINGS

| CHARACTERISTIC | SYMBOL | RATING | UNIT |
|------------------------------------|------------------|---------------------------|------|
| Supply Voltage Range | V _{CC} | -0.5~7.0 | V |
| DC Input Voltage | VIN | -0.5~7.0 | V |
| DC Output Voltage | Vout | -0.5~V _{CC} +0.5 | V |
| Input Diode Current | ΙΚ | - 20 | mA |
| Output Diode Current | lok | ± 20 | mA |
| DC Output Current | lout | ± 25 | mA |
| DC V _{CC} /Ground Current | lcc | ± 50 | mA |
| Power Dissipation | PD | 200 | mW |
| Storage Temperature | T _{stg} | -65∼150 | °C |
| Lead Temperature (10 s) | TL | 260 | °C |

MARKING



TRUTH TABLE

| Α | Υ |
|---|---|
| L | Н |
| Н | L |

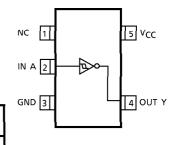
LOGIC DIAGRAM



RECOMMENDED OPERATING CONDITIONS

| CHARACTERISTIC | SYMBOL | RATING | UNIT |
|--------------------------|------------------|--|--------|
| Supply Voltage | Vcc | 2.0~5.5 | V |
| Input Voltage | VIN | 0~5.5 | V |
| Output Voltage | Vout | 0~V _{CC} | V |
| Operating Temperature | T _{opr} | - 40~85 | °C |
| Input Rise and Fall Time | dt/dv | $0 \sim 100 \text{ (V}_{CC} = 3.3 \pm 0.3 \text{V)}$ | ns/V |
| | at/av | $0\sim20 (V_{CC} = 5 \pm 0.5V)$ | 115/ V |

PIN ASSIGNMENT (TOP VIEW)



DC ELECTRICAL CHARACTERISTICS

| CHARACTERISTIC SYMBOL | | TEST CONDITION | | | 7 | Га = 25°(| С | Ta = -40~85°C | | UNIT |
|-------------------------------|-----------------|--|-------------------------|-----------|------|-----------|------|---------------|-------|-------|
| | | | | Vcc | MIN. | TYP. | MAX. | MIN. | MAX. | LUNIT |
| Positive Threshold | | | | 3.0 | _ | _ | 2.20 | _ | 2.20 | V |
| Positive Threshold Voltage | V _P | | | 4.5 | _ | _ | 3.15 | _ | 3.15 | |
| Voitage | | | | 5.5 | _ | _ | 3.85 | | 3.85 | |
| Negative Threshold | | | | 3.0 | 0.90 | _ | _ | 0.90 | _ | |
| Voltage | ٧N | | | 4.5 | 1.35 | _ | _ | 1.35 | _ | V |
| Voitage | | | | 6.0 | 1.65 | _ | _ | 1.65 | _ | |
| | | | | | 0.30 | _ | 1.20 | 0.30 | 1.20 | ٧ |
| Hysteresis Voltage | VH | | | 4.5 | 0.40 | _ | 1.40 | 0.40 | 1.40 | |
| | | | | 5.5 | 0.50 | _ | 1.60 | 0.50 | 1.60 | |
| | V _{ОН} | V _{IN} = V _{IL} | I _{OH} = -50μA | 2.0 | 1.9 | 2.0 | _ | 1.9 | | V |
| High-Level | | | | 3.0 | 2.9 | 3.0 | _ | 2.9 | | |
| Output Voltage | | | | 4.5 | 4.4 | 4.5 | _ | 4.4 | | |
| | | | $I_{OH} = -4mA$ | 3.0 | 2.58 | _ | _ | 2.48 | _ | |
| | | | $I_{OH} = -8mA$ | 4.5 | 3.94 | _ | _ | 3.80 | _ | |
| | | V _{IN} = V _{IH} | I _{OL} = 50 μA | 2.0 | | 0.0 | 0.1 | _ | 0.1 | |
| Low-Level Output Voltage | | | | 3.0 | | 0.0 | 0.1 | _ | 0.1 | |
| | VOL | | | 4.5 | _ | 0.0 | 0.1 | _ | 0.1 | |
| | | | $I_{OL} = 4mA$ | 3.0 | _ | _ | 0.36 | _ | 0.44 | |
| | | | $I_{OL} = 8mA$ | 4.5 | _ | _ | 0.36 | _ | 0.44 | |
| Input Leakage Current | IN | V _{IN} = 5.5V or GND | | 0~ 5.5 | _ | _ | ±0.1 | _ | ± 1.0 | μΑ |
| Quiescent Supply Current | lcc | V _{IN} = V _{CC} or GND | | 5.5 | | _ | 2.0 | _ | 20.0 | μΑ |

2 2001-05-31

AC ELECTRICAL CHARACTERISTICS (Input $t_r = t_f = 3ns$)

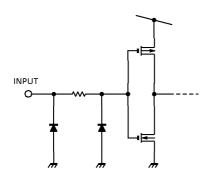
| CHARACTERISTIC | SYMBOL | TEST C | TEST CONDITION | | | Ta = 25°C | | | $Ta = -40 \sim 85^{\circ}C$ | |
|---------------------------|----------------------|------------|---------------------|---------------------|------|-----------|------|------|-----------------------------|------|
| CHARACTERISTIC 3 | STIVIBUL | | V _{CC} (V) | C _L (pF) | MIN. | TYP. | MAX. | MIN. | MAX. | UNIT |
| Propagation Delay Time | | | 22402 | 15 | | 8.3 | 12.8 | 1.0 | 15.0 | - ns |
| | t _{pLH} | | 3.3 ± 0.3 | 50 | _ | 10.8 | 16.3 | 1.0 | 18.5 | |
| | tpHL | | 5.0 ± 0.5 | 15 | _ | 5.5 | 8.6 | 1.0 | 10.0 | |
| | · | | | 50 | _ | 7.0 | 10.6 | 1.0 | 12.0 | |
| Input Capacitance | C _{IN} | | | | | 4 | 10 | _ | 10 | pF |
| Power Dissipation | Power Dissipation (N | | ote 1) | | | 21 | | | | pF |
| Capacitance | C _{PD} | באם (ווי | | | | 21 | | _ | | рг |

(Note 1): CpD is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

Average operating current can be obtained by the equation:

$$I_{CC (opr)} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}$$

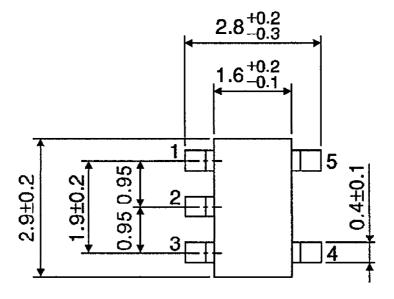
INPUT EQUIVALENT CIRCUIT

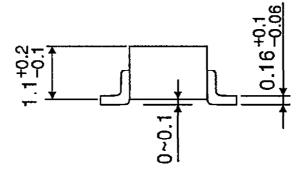


PACKAGE DIMENSIONS

SSOP5-P-0.95

Unit: mm





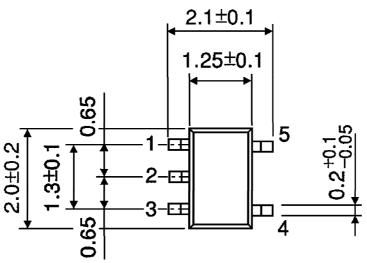
Weight: 0.016g (Typ.)

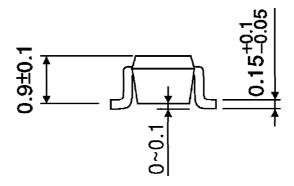
4 2001-05-31

Unit: mm

PACKAGE DIMENSIONS

SSOP5-P-0.65A





Weight: 0.006g (Typ.)

5 2001-05-31

RESTRICTIONS ON PRODUCT USE

000707EBA

- TOSHIBA is continually working to improve the quality and reliability of its products. Nevertheless, semiconductor devices in general can malfunction or fail due to their inherent electrical sensitivity and vulnerability to physical stress. It is the responsibility of the buyer, when utilizing TOSHIBA products, to comply with the standards of safety in making a safe design for the entire system, and to avoid situations in which a malfunction or failure of such TOSHIBA products could cause loss of human life, bodily injury or damage to property. In developing your designs, please ensure that TOSHIBA products are used within specified operating ranges as set forth in the most recent TOSHIBA products specifications. Also, please keep in mind the precautions and conditions set forth in the "Handling Guide for Semiconductor Devices," or "TOSHIBA Semiconductor Reliability Handbook" etc..
- The TOSHIBA products listed in this document are intended for usage in general electronics applications (computer, personal equipment, office equipment, measuring equipment, industrial robotics, domestic appliances, etc.). These TOSHIBA products are neither intended nor warranted for usage in equipment that requires extraordinarily high quality and/or reliability or a malfunction or failure of which may cause loss of human life or bodily injury ("Unintended Usage"). Unintended Usage include atomic energy control instruments, airplane or spaceship instruments, transportation instruments, traffic signal instruments, combustion control instruments, medical instruments, all types of safety devices, etc.. Unintended Usage of TOSHIBA products listed in this document shall be made at the customer's own risk.
- The products described in this document are subject to the foreign exchange and foreign trade laws.
- ◆ The information contained herein is presented only as a guide for the applications of our products. No responsibility is assumed by TOSHIBA CORPORATION for any infringements of intellectual property or other rights of the third parties which may result from its use. No license is granted by implication or otherwise under any intellectual property or other rights of TOSHIBA CORPORATION or others.
- The information contained herein is subject to change without notice.